/ Descriptions

SOD-323

Zener Diode in a SOD-323 Plastic Package.

/ Features

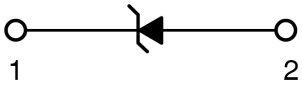
200mW

200mW Power dissipation, medium current, automated assembly processes,HF Product.

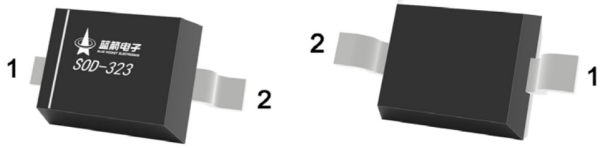
/ Applications

2.4V to 39V wide zener voltage range applications.

/ Equivalent Circuit



/ Pinning



PIN1:Cathode PIN2:Anode

/ Marking

See Electrical Characteristics.

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Forward Voltage (Note 2) (I_F=10mA)	V_F	0.9	V
Power Dissipation(Note 1)	P_D	200	mW
Typical Thermal Resistance Junction to Ambient(Note 1)	$R_{\theta JA}$	625	/W
Junction and Storage Temperature Range	T_j,T_{stg}	-65 150	

/ Electrical Characteristics(Ta=25)

Type Number	Mark-ing Code	Zener Voltage Range (Note 2)				Maximum Zener mpedance (Note 3)			Maximum Reverse Current (Note 2)		Typical Temperature Coefficient @I_{ZTC} mV/ºC		Test Current I_{ZTC}
		V_z @I_{ZT}			I_{ZT}	Z_{ZT} @I_{ZT}	Z_{ZK} @I_{ZK}	I_{ZK}	I_R	@V_R			
		Nom (V)	Min (V)	Max (V)	mA	Ω		mA	uA	V	Min	Max	mA
BZT52C2V4S	HWX	2.4	2.2	2.6	5	100	600	1	50	1	-3.5	0	5
BZT52C2V7S	HW1	2.7	2.5	2.9	5	100	600	1	20	1	-3.5	0	5
BZT52C3V0S	HW2	3.0	2.8	3.2	5	95	600	1	10	1	-3.5	0	5
BZT52C3V3S	HW3	3.3	3.1	3.5	5	95	600	1	5	1	-3.5	0	5
BZT52C3V6S	HW4	3.6	3.4	3.8	5	90	600	1	5	1	-3.5	0	5
BZT52C3V9S	HW5	3.9	3.7	4.1	5	90	600	1	3	1	-3.5	0	5
BZT52C4V3S	HW6	4.3	4	4.6	5	90	600	1	3	1	-3.5	0	5
BZT52C4V7S	HW7	4.7	4.4	5	5	80	500	1	3	2	-3.5	0.2	5
BZT52C5V1S	HW8	5.1	4.8	5.4	5	60	480	1	2	2	-2.7	1.2	5
BZT52C5V6S	HW9	5.6	5.2	6	5	40	400	1	1	2	-2	2.5	5
BZT52C6V2S	HWA	6.2	5.8	6.6	5	10	150	1	3	4	0.4	3.7	5
BZT52C6V8S	HWB	6.8	6.4	7.2	5	15	80	1	2	4	1.2	4.5	5
BZT52C7V5S	HWC	7.5	7	7.9	5	15	80	1	1	5	2.5	5.3	5
BZT52C8V2S	HWD	8.2	7.7	8.7	5	15	80	1	0.7	5	3.2	6.2	5
BZT52C9V1S	HWE	9.1	8.5	9.6	5	15	100	1	0.5	6	3.8	7	5
BZT52C10S	HWF	10	9.4	10.6	5	20	150	1	0.2	7	4.5	8	5

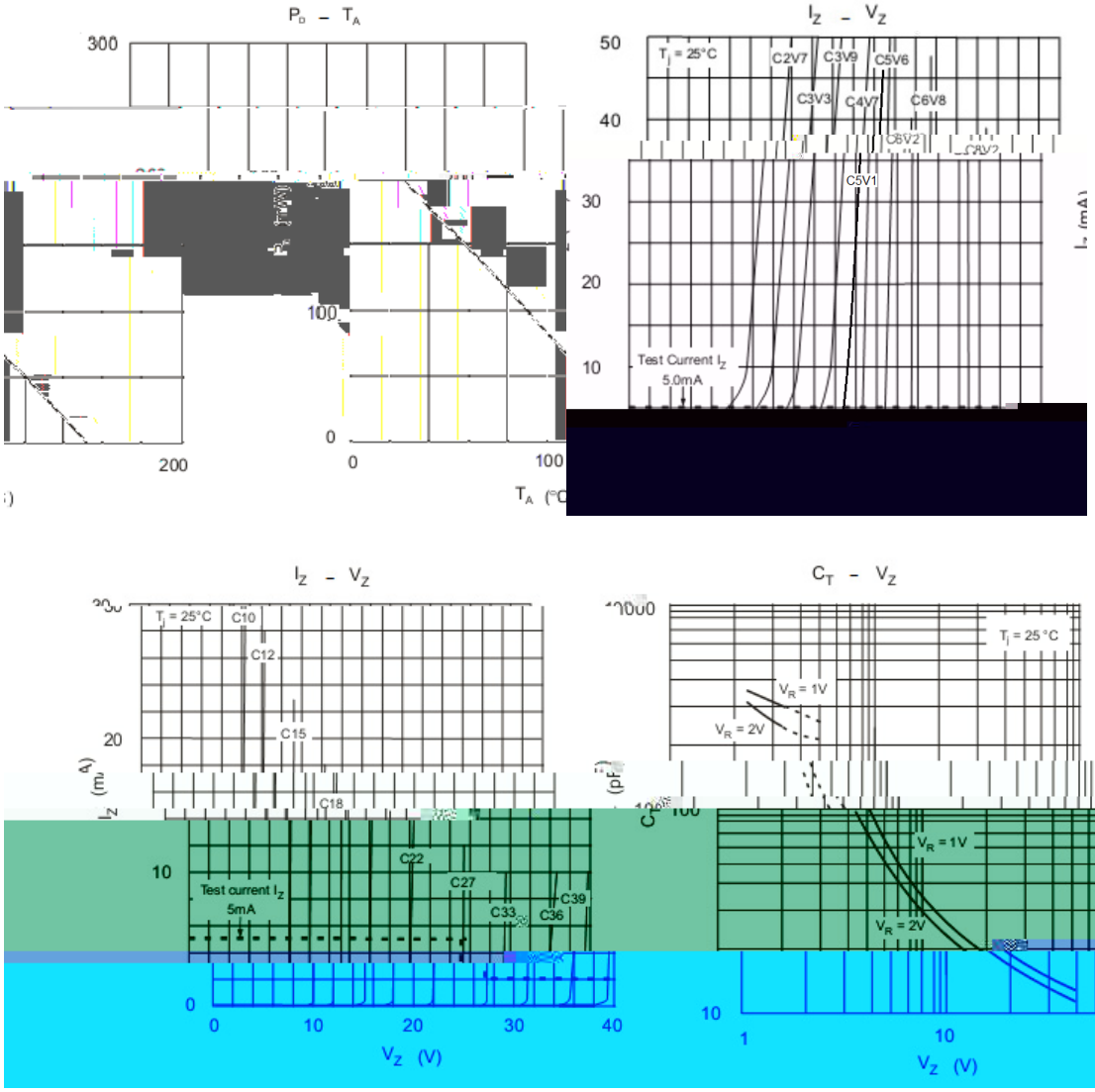
/ Electrical Characteristics(Ta=25)

Type Number	Marking Code	Zener Voltage Range (Note 2)				Maximum Zener mpedance (Note 3)			Maximum Reverse Current (Note 2)		Typical Temperature Coefficient @I_{ZTC} mV/ºC		Test Curre nt I_{ZTC}
		V_z @I_{ZT}			I_{ZT}	Z_{ZT} @I_{ZT}	Z_{ZK} @I_{ZK}	I_{ZK}	I_R	@V_R			
		Nom (V)	Min (V)	Max (V)	mA	Ω		mA	uA	V	Min	Max	mA
BZT52C11S	HWG	11	10.4	11.6	5	20	150	1	0.1	8	5.4	9	5
BZT52C12S	HWH	12	11.4	12.7	5	25	150	1	0.1	8	6	10	5
BZT52C13S	HWI	13	12.4	14.1	5	30	170	1	0.1	8	7	11	5
BZT52C15S	HWJ	15	13.8	15.6	5	30	200	1	0.1	10.5	9.2	13	5
BZT52C16S	HWK	16	15.3	17.1	5	40	200	1	0.1	11.2	10.4	14	5
BZT52C18S	HWL	18	16.8	19.1	5	45	225	1	0.1	12.6	12.4	16	5
BZT52C20S	HWM	20	18.8	21.2	5	55	225	1	0.1	14	14.4	18	5
BZT52C22S	HWN	22	20.8	23.3	5	55	250	1	0.1	15.4	16.4	20	5
BZT52C24S	HWO	24	22.8	25.6	5	70	250	1	0.1	16.8	18.4	22	5
BZT52C27S	HWP	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3	2
BZT52C30S	HWQ	30	28	32	2	80	300	0.5	0.1	21	24.4	29.4	2
BZT52C33S	HWR	33	31	35	2	80	325	0.5	0.1	23.1	27.4	33.4	2
BZT52C36S	HWS	36	34	38	2	90	350	0.5	0.1	25.2	30.4	37.4	2
BZT52C39S	HWT	39	37	41	2	130	350	0.5	0.1	27.3	33.4	41.2	2

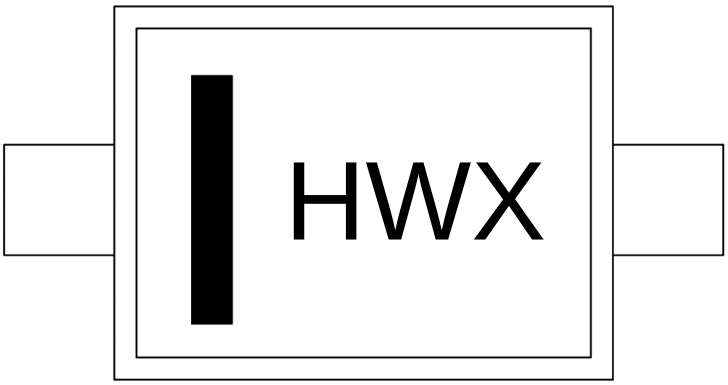
Notes:

1. Device mounted on ceramic PCB; 7.6mm x 9.4mm x 0.87mm with pad areas 25mm^2.
2. Short duration test pulse used to minimize self-heating effect.
3. f = 1kHz.

/ Electrical Characteristic Curve



/ Marking Instructions



Note:

H: Company Code

WX: Product Type Code

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)

		Note:
1	150 180 60 90sec;	1.Preheating:150~180 , Time:60~90sec.
2	245 5 5 0.5sec;	2.Peak Temp.:245 5 , Duration:5 0.5sec.
3	2 10 /sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260 5	10 1 sec.	Temp.:260±5	Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension		(unit mm³)
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box